# Howard M Branz

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104 3,404 29 57 g-index h-index citations papers 6.9 111 5.31 3,723 avg, IF L-index ext. citations ext. papers

#	Paper	IF	Citations
104	An 18.2%-efficient black-silicon solar cell achieved through control of carrier recombination in nanostructures. <i>Nature Nanotechnology</i> , <b>2012</b> , 7, 743-8	28.7	678
103	Efficient black silicon solar cell with a density-graded nanoporous surface: Optical properties, performance limitations, and design rules. <i>Applied Physics Letters</i> , <b>2009</b> , 95, 123501	3.4	254
102	Nanostructured black silicon and the optical reflectance of graded-density surfaces. <i>Applied Physics Letters</i> , <b>2009</b> , 94, 231121	3.4	253
101	Hydrogen collision model: Quantitative description of metastability in amorphous silicon. <i>Physical Review B</i> , <b>1999</b> , 59, 5498-5512	3.3	206
100	Nanoporous black silicon photocathode for H2 production by photoelectrochemical water splitting. <i>Energy and Environmental Science</i> , <b>2011</b> , 4, 1690	35.4	199
99	Potential fluctuations due to inhomogeneity in hydrogenated amorphous silicon and the resulting charged dangling-bond defects. <i>Physical Review B</i> , <b>1990</b> , 42, 7420-7428	3.3	133
98	Multi-scale surface texture to improve blue response of nanoporous black silicon solar cells. <i>Applied Physics Letters</i> , <b>2011</b> , 99, 103501	3.4	126
97	Stand-alone photovoltaic-powered electrochromic smart window. <i>Electrochimica Acta</i> , <b>2001</b> , 46, 2125-2	1639	93
96	Hydrogen collision model of light-induced metastability in hydrogenated amorphous silicon. <i>Solid State Communications</i> , <b>1998</b> , 105, 387-391	1.6	78
95	Angle-resolved XPS analysis and characterization of monolayer and multilayer silane films for DNA coupling to silica. <i>Langmuir</i> , <b>2013</b> , 29, 4057-67	4	72
94	Exciton splitting and carrier transport across the amorphous-silicon/polymer solar cell interface. <i>Applied Physics Letters</i> , <b>2006</b> , 89, 252102	3.4	67
93	Light-enhanced deep deuterium emission and the diffusion mechanism in amorphous silicon. <i>Physical Review B</i> , <b>1993</b> , 47, 7061-7066	3.3	56
92	Reformulation of solar cell physics to facilitate experimental separation of recombination pathways. <i>Applied Physics Letters</i> , <b>2013</b> , 103, 093502	3.4	53
91	Exciton harvesting, charge transfer, and charge-carrier transport in amorphous-silicon nanopillar/polymer hybrid solar cells. <i>Journal of Applied Physics</i> , <b>2008</b> , 103, 064511	2.5	50
90	Dangling bonds in doped amorphous silicon: Equilibrium, relaxation, and transition energies. <i>Physical Review B</i> , <b>1989</b> , 39, 5107-5115	3.3	47
89	Efficient nanostructured BlackBilicon solar cell by copper-catalyzed metal-assisted etching. <i>Progress in Photovoltaics: Research and Applications</i> , <b>2015</b> , 23, 1375-1380	6.8	46
88	Hydrogen diffusion and mobile hydrogen in amorphous silicon. <i>Physical Review B</i> , <b>1999</b> , 60, 7725-7727	3.3	46

### (1998-1993)

87	Dangling-bond relaxation and deep-level measurements in hydrogenated amorphous silicon. <i>Physical Review B</i> , <b>1993</b> , 48, 8667-8671	3.3	42
86	Material quality requirements for efficient epitaxial film silicon solar cells. <i>Applied Physics Letters</i> , <b>2010</b> , 96, 073502	3.4	37
85	Atomic structure and electronic properties of c-Si\(\text{B}\)-Si:H heterointerfaces. <i>Applied Physics Letters</i> , <b>2006</b> , 88, 121925	3.4	36
84	Heteroepitaxial film silicon solar cell grown on Ni-W foils. <i>Energy and Environmental Science</i> , <b>2012</b> , 5, 6052	35.4	35
83	Explanation of the limiting thickness observed in low-temperature silicon epitaxy. <i>Applied Physics Letters</i> , <b>2000</b> , 77, 3589-3591	3.4	35
82	Monitoring and modeling silicon homoepitaxy breakdown with real-time spectroscopic ellipsometry. <i>Journal of Applied Physics</i> , <b>2005</b> , 97, 103536	2.5	34
81	Proton Reduction Using a Hydrogenase-Modified Nanoporous Black Silicon Photoelectrode. <i>ACS Applied Materials &amp; Applied &amp; Applied Materials &amp; Applied &amp; Appl</i>	9.5	33
80	Hot-wire chemical vapor deposition of epitaxial film crystal silicon for photovoltaics. <i>Thin Solid Films</i> , <b>2011</b> , 519, 4545-4550	2.2	33
79	Heteroepitaxial film crystal silicon on Al2O3: new route to inexpensive crystal silicon photovoltaics. <i>Energy and Environmental Science</i> , <b>2011</b> , 4, 3346	35.4	32
78	On the superlinear increase in conductivity with dopant concentration in excitonic semiconductors. <i>Applied Physics Letters</i> , <b>2004</b> , 84, 1707-1709	3.4	32
77	Hydrogen above saturation at silicon vacancies: H-pair reservoirs and metastability sites. <i>Physical Review Letters</i> , <b>2001</b> , 87, 105503	7.4	31
76	Capacitance-spectroscopy identification of a key defect in N-degraded GalnNAs solar cells. <i>Applied Physics Letters</i> , <b>2005</b> , 86, 113506	3.4	29
75	Light-induced D diffusion measurements in hydrogenated amorphous silicon: Testing H metastability models. <i>Physical Review B</i> , <b>1999</b> , 59, 5513-5520	3.3	28
74	Hydrogen diffusion in a-Si:H: Solution of the tracer equations including capture by exchange. <i>Physical Review B</i> , <b>1995</b> , 52, 13946-13954	3.3	28
73	Light trapping by a dielectric nanoparticle back reflector in film silicon solar cells. <i>Applied Physics Letters</i> , <b>2011</b> , 99, 064101	3.4	27
72	Significant improvement in silicon chemical vapor deposition epitaxy above the surface dehydrogenation temperature. <i>Journal of Applied Physics</i> , <b>2006</b> , 100, 093520	2.5	26
71	Biaxially-textured photovoltaic film crystal silicon on ion beam assisted deposition CaF2 seed layers on glass. <i>Energy and Environmental Science</i> , <b>2012</b> , 5, 6905	35.4	25
70	Monolithic, Self-Powered Photovoltaic-Electrochromic Coating for Windows. <i>Journal of the Electrochemical Society</i> , <b>1998</b> , 145, 3545-3550	3.9	22

69	The hydrogen collision model of metastability after 5 years: experimental tests and theoretical extensions. <i>Solar Energy Materials and Solar Cells</i> , <b>2003</b> , 78, 425-445	6.4	21
68	Pyramidal light trapping and hydrogen passivation for high-efficiency heteroepitaxial (100) crystal silicon solar cells. <i>Energy and Environmental Science</i> , <b>2012</b> , 5, 8193	35.4	20
67	High-resolution X-ray photoelectron spectroscopy of mixed silane monolayers for DNA attachment. <i>ACS Applied Materials &amp; DNA attachment</i> , 3, 3285-92	9.5	20
66	Nonradiative electron-hole recombination by a low-barrier pathway in hydrogenated silicon semiconductors. <i>Physical Review Letters</i> , <b>2000</b> , 84, 967-70	7.4	19
65	Mechanisms controlling the phase and dislocation density in epitaxial silicon films grown from silane below 800 °C. <i>Applied Physics Letters</i> , <b>2010</b> , 96, 201901	3.4	17
64	Electron beam creation of metastable defects in hydrogenated amorphous silicon: hydrogen collision model. <i>Journal of Non-Crystalline Solids</i> , <b>2000</b> , 266-269, 437-443	3.9	16
63	Cone kinetics model for two-phase film silicon deposition. <i>Applied Physics Letters</i> , <b>2008</b> , 92, 093114	3.4	15
62	Fermi-level dependence of the charge state of diffusing hydrogen in amorphous silicon. <i>Journal of Non-Crystalline Solids</i> , <b>2002</b> , 299-302, 191-195	3.9	13
61	Excellent passivation and low reflectivity Al2O3 /TiO2 bilayer coatings for n-wafer silicon solar cells <b>2012</b> ,		11
60	Fingerprints of two distinct defects causing light-induced photoconductivity degradation in hydrogenated amorphous silicon. <i>Applied Physics Letters</i> , <b>2001</b> , 79, 3080-3082	3.4	11
59	Physics and chemistry of hot-wire chemical vapor deposition from silane: Measuring and modeling the silicon epitaxy deposition rate. <i>Journal of Applied Physics</i> , <b>2010</b> , 107, 054906	2.5	10
58	Electron transport and band structure in phosphorus-doped polycrystalline silicon films. <i>Journal of Applied Physics</i> , <b>2009</b> , 105, 033715	2.5	10
57	Anneal treatment to reduce the creation rate of light-induced metastable defects in device-quality hydrogenated amorphous silicon. <i>Applied Physics Letters</i> , <b>2011</b> , 98, 201908	3.4	10
56	Comment on "Excitation-energy dependence of optically induced ESR in a-Si:H". <i>Physical Review B</i> , <b>1990</b> , 41, 7887-7890	3.3	10
55	Comparison of thin epitaxial film silicon photovoltaics fabricated on monocrystalline and polycrystalline seed layers on glass. <i>Progress in Photovoltaics: Research and Applications</i> , <b>2015</b> , 23, 909-	-9 <del>17</del> 8	9
54	Solid phase crystallization of hot-wire CVD amorphous silicon films. <i>Materials Research Society Symposia Proceedings</i> , <b>2005</b> , 862, 1051		9
53	Efficient 18		9
52	Improved stability of hydrogenated amorphous-silicon photosensitivity by ultraviolet illumination. <i>Applied Physics Letters</i> , <b>2002</b> , 81, 3353-3355	3.4	8

# (1994-2000)

51	The hydrogen collision model: theory and experiment. <i>Journal of Non-Crystalline Solids</i> , <b>2000</b> , 266-269, 391-396	3.9	8
50	Device Physics of Heteroepitaxial Film c-Si Heterojunction Solar Cells. <i>IEEE Journal of Photovoltaics</i> , <b>2013</b> , 3, 230-235	3.7	7
49	Physics of the Meyer-Neldel Rule in Amorphous Silicon. <i>Materials Research Society Symposia Proceedings</i> , <b>1994</b> , 336, 159		7
48	Epitaxial crystal silicon absorber layers and solar cells grown at 1.8 microns per minute <b>2011</b> ,		6
47	Dislocation-limited open circuit voltage in film crystal silicon solar cells. <i>Applied Physics Letters</i> , <b>2012</b> , 101, 123510	3.4	6
46	Measurement of electric-field induced second harmonic generation in hydrogenated amorphous silicon. <i>Applied Physics Letters</i> , <b>2012</b> , 101, 161604	3.4	6
45	Real Time Monitoring of the Crystallization of Hydrogenated Amorphous Silicon. <i>Materials Research Society Symposia Proceedings</i> , <b>2005</b> , 862, 1611		6
44	Structural Changes in a-Si:H Studied by X-Ray Photoemission Spectroscopy. <i>Materials Research Society Symposia Proceedings</i> , <b>1999</b> , 557, 359		6
43	Structural Relaxation and Structural Memory at Amorphous Silicon Dangling Bonds. <i>Materials Research Society Symposia Proceedings</i> , <b>1994</b> , 336, 129		6
42	Novel Micropixelation Strategy to Stabilize Semiconductor Photoelectrodes for Solar Water Splitting Systems. <i>Journal of Physical Chemistry C</i> , <b>2012</b> , 116, 19262-19267	3.8	5
41	Efficient black silicon solar cells with nanoporous anti-reflection made in a single-step liquid etch <b>2009</b> ,		5
40	Switching Behavior in p-Type Hydrogenated Amorphous Silicon with One and Two Blocking Contacts. <i>Materials Research Society Symposia Proceedings</i> , <b>2002</b> , 715, 1221		5
39	Hydrogen Diffusion Mechanism in Amorphous Silicon from D Tracer Diffusion: Theory and Experiment. <i>Materials Research Society Symposia Proceedings</i> , <b>1993</b> , 297, 279		5
38	600 mV epitaxial crystal silicon solar cells grown on seeded glass <b>2013</b> ,		4
37	Comparative Study of Solid-Phase Crystallization of Amorphous Silicon Deposited by Hot-wire CVD, Plasma-Enhanced CVD, and Electron-Beam Evaporation. <i>Materials Research Society Symposia Proceedings</i> , <b>2007</b> , 989, 4		4
36	Silicon homoepitaxy using tantalum-filament hot-wire chemical vapor deposition. <i>Materials Research Society Symposia Proceedings</i> , <b>2005</b> , 862, 231		4
35	Hydrogen Collision Model of The Staebler-Wronski Effect: Microscopics and Kinetics. <i>Materials Research Society Symposia Proceedings</i> , <b>1998</b> , 507, 709		4
34	On Modeling Trivalent Dangling Bonds with Bivalent Levels. <i>Materials Research Society Symposia</i> Proceedings, <b>1994</b> , 336, 153		4

33	Microstructure and surface chemistry of nanoporous Black silicon[for photovoltaics 2010,		3
32	Improved Monolithic Photovoltaic-Electrochromic Devices Incorporating an a-SiC:H Solar Cell. <i>Materials Research Society Symposia Proceedings</i> , <b>1996</b> , 420, 183		3
31	Evidence for Exchange Between Free and Deep Hydrogen (Deuterium) During Diffusion. <i>Materials Research Society Symposia Proceedings</i> , <b>1995</b> , 377, 331		3
30	Silicon solar cells with front hetero-contact and aluminum alloy back junction. <i>Conference Record of the IEEE Photovoltaic Specialists Conference</i> , <b>2008</b> ,		2
29	The Effect of Oxygen Contamination on the Electronic Properties of Hot-Wire CVD Amorphous Silicon Germanium Alloys. <i>Materials Research Society Symposia Proceedings</i> , <b>2006</b> , 910, 5		2
28	Physics of Solid-Phase Epitaxy of Hydrogenated Amorphous Silicon for Thin Film Si Photovoltaics. <i>Materials Research Society Symposia Proceedings</i> , <b>2006</b> , 910, 5		2
27	Roughness, impurities and strain in low-temperature epitaxial silicon films grown by tantalum filament hot-wire chemical vapor deposition. <i>Materials Research Society Symposia Proceedings</i> , <b>2006</b> , 910, 1		2
26	Dependence of the Electronic Properties of Hot-Wire CVD Amorphous Silicon-Germanium Alloys on Oxygen Impurity Levels. <i>Materials Research Society Symposia Proceedings</i> , <b>2007</b> , 989, 3		2
25	Area-Dependent Switching in Thin Film-Silicon Devices. <i>Materials Research Society Symposia Proceedings</i> , <b>2003</b> , 762, 1831		2
24	New experiments on the relationship between light-induced defects and photoconductivity degradation. <i>Materials Research Society Symposia Proceedings</i> , <b>2001</b> , 664, 1221		2
23	Hydrogen Equilibration and Metastability in Amorphous Silicon. <i>Materials Research Society Symposia Proceedings</i> , <b>2001</b> , 664, 1331		2
22	Slow Degradation of Hydrogenated Amorphous Silicon Photoconductivity Under Pulsed Illumination. <i>Materials Research Society Symposia Proceedings</i> , <b>1999</b> , 557, 347		2
21	On the lack of observable light-induced H diffusion near room temperature. <i>Journal of Non-Crystalline Solids</i> , <b>1996</b> , 198-200, 441-444	3.9	2
20	Observation of Metastability in Amorphous Silicon Containing 0.1 at.% Hydrogen. <i>Materials Research Society Symposia Proceedings</i> , <b>1992</b> , 258, 389		2
19	Improved 750 LC epitaxial crystal silicon solar cells through impurity reduction 2013,		1
18	Light trapping for thin silicon solar cells by femtosecond laser texturing 2012,		1
17	2012,		1
16	Photovoltaic device characterization with optical second harmonic generation 2010,		1

#### LIST OF PUBLICATIONS

15	Phase evolution in nanocrystalline silicon films: Hydrogen dilution and the cone kinetics model. <i>Philosophical Magazine</i> , <b>2009</b> , 89, 2461-2468	1.6	1
14	Device physics of heteroepitaxial film c-Si heterojunction solar cells <b>2012</b> ,		1
13	Pulsed-illumination study of metastable defect creation time scales in hydrogenated amorphous silicon. <i>Physical Review B</i> , <b>2004</b> , 69,	3.3	1
12	Metastable defects by low-intensity pulsed illumination of hydrogenated amorphous silicon. <i>Materials Research Society Symposia Proceedings</i> , <b>2000</b> , 609, 321		1
11	Hydrogen Diffusion in the Hydrogen Collision Model of Amorphous Silicon Metastability. <i>Materials Research Society Symposia Proceedings</i> , <b>1999</b> , 557, 377		1
10	Light Bias CPM Study of the Density of States in N-Type Amorphous Silicon. <i>Materials Research Society Symposia Proceedings</i> , <b>1996</b> , 420, 703		1
9	Wide GAP a-SiC:H Alloys for Novel Photovoltaic-Electrochromic Window Coatings. <i>Materials Research Society Symposia Proceedings</i> , <b>1995</b> , 377, 589		1
8	New Results on Enhanced Deuterium Diffusion Under Illumination in Amorphous Silicon. <i>Materials Research Society Symposia Proceedings</i> , <b>1992</b> , 258, 431		1
7	Amorphous to Microcrystalline Transition in Thickness-graded Hot-Wire CVD Silicon Films. <i>Materials Research Society Symposia Proceedings</i> , <b>2002</b> , 715, 1711		1
6	Materials Optimization for Silicon Heterojunction Solar Cells Using Spectroscopic Ellipsometry. <i>Materials Research Society Symposia Proceedings</i> , <b>2007</b> , 989, 4		
5	Increase of temperature and crystallinity during electrical switching in microcrystalline silicon. <i>Materials Research Society Symposia Proceedings</i> , <b>2004</b> , 808, 185		
4	Photoconductivity Stability Improvement in Hydrogenated Amorphous Silicon by Ultraviolet Illumination. <i>Materials Research Society Symposia Proceedings</i> , <b>2002</b> , 715, 19111		
3	Combinatorial Studies of Switching and Solid-Phase Crystallization in Amorphous Silicon. <i>Materials Research Society Symposia Proceedings</i> , <b>2005</b> , 894, 1		
2	Determination of the Mobile-Hydrogen Charge State in Hydrogenated Amorphous Silicon. <i>Materials Research Society Symposia Proceedings</i> , <b>2001</b> , 664, 2821		
1	Monte Carlo Simulations of Defect Relaxation in Amorphous Silicon. <i>Materials Research Society Symposia Proceedings</i> , <b>1995</b> , 377, 293		